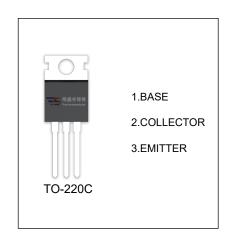


## TIP31/31A/31B/31C TRANSISTOR (NPN)

## **FEATURES**

Medium Power Linear Switching Applications



## MAXIMUM RATINGS (Ta=25℃ unless otherwise noted)

Symbol	Parameter	TIP31	TIP31A	TIP31B	TIP31C	Unit
V <sub>CBO</sub>	Collector-Base Voltage	40	60	80	100	V
V <sub>CEO</sub>	Collector-Emitter Voltage	40	60	80	100	V
V <sub>EBO</sub>	Emitter-Base Voltage	5				V
Ic	Collector Current	3				Α
Pc	Collector Power Dissipation	2				W
R <sub>0JA</sub>	Thermal Resistance from Junction to Ambient	62.5			°C/W	
$T_j, T_{stg}$	Operation Junction and Storage Temperature Range	-55~+150			°C	

## **ELECTRICAL CHARACTERISTICS (Ta=25℃ unless other wise specified)**

Parameter	Symbol	Test conditions	Min	Max	Unit
Collector-base breakdown voltage TIP31 TIP311 TIP310	V(BR)CBO	I <sub>C</sub> = 1mA, I <sub>E</sub> =0	40 60 80 100		V
Collector-emitter breakdown voltage * TIP31 TIP314 TIP316 TIP316	V <sub>CEO(sus)</sub>	I <sub>C</sub> = 30mA, I <sub>B</sub> =0	40 60 80 100		V
Emitter-base breakdown voltage	V(BR)EBO	I <sub>E</sub> = 1mA, I <sub>C</sub> =0	5		V
Collector cut-off current TIP31 TIP318 TIP318	I <sub>CBO</sub>	$V_{CB}$ =40V, $I_{E}$ =0 $V_{CB}$ =60V, $I_{E}$ =0 $V_{CB}$ =80V, $I_{E}$ =0 $V_{CB}$ =100V, $I_{E}$ =0		200	μΑ
Collector cut-off current TIP31/31/ TIP31B/310	-	V <sub>CE</sub> = 30V, I <sub>B</sub> = 0 V <sub>CE</sub> = 60V, I <sub>B</sub> = 0		0.3	mA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> =5V, I <sub>C</sub> =0		1	mA
DC current gain	h <sub>FE(1)</sub>	V <sub>CE</sub> = 4V, I <sub>C</sub> = 1A V <sub>CE</sub> =4 V, I <sub>C</sub> = 3A	25 15	75	
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =3A, I <sub>B</sub> =0.375A		1.2	V
Base-emitter voltage	V <sub>BE(on)</sub>	V <sub>CE</sub> = 4V, I <sub>C</sub> =3A		1.8	V
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> =10V , I <sub>C</sub> =0.5A	3		MHz

<sup>\*</sup> Pulse Test: PW≤300µs, Duty Cycle≤2%.



